NSN 5961-01-384-6933

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-384-6933 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.340 inches Overall Diameter: 0.620 inches **Internal Configuration:** Field effect **Electrode Internally-electrically Connected To Case:** Drain **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 drain to source voltage and 100.0 drain to gate voltage **Current Rating Per Characteristic:** -15.00 amperes source current **Power Rating Per Characteristic:** 70.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 pin **Specification Data:** 81349-mil-s-19500/569 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No